

# 2.5V CMOS 1-TO-10 CLOCK DRIVER

## IDT74FCT20807

## **FEATURES:**

- High frequency > 150MHz
- Guaranteed low skew < 150ps (max.) between any two outputs
- Very low duty cycle distortion < 300ps
- · High speed: propagation delay < 3ns
- Very low CMOS power levels
- TTL compatible inputs and outputs
- 1:10 fanout
- · Maximum output rise and fall time < 1.25ns (max.)
- · Low input capacitance: 3pF typical
- · 2.5V supply voltage
- · Available in SSOP and QSOP packages

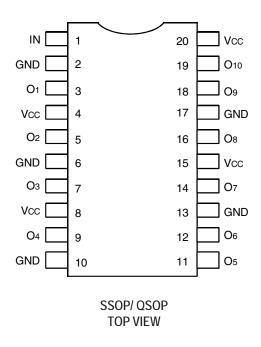
## **DESCRIPTION:**

The FCT20807 is a 2.5V compatible, high speed, low noise, 1:10 fanout, non-inverting clock buffer. The large fanout from a single input reduces loading on the preceding driver and provides an efficient clock distribution network. Providing output to output skew as low as 150ps, the FCT20807 is an ideal clock distribution device for synchronous systems. Multiple power and grounds reduce noise. Typical applications are clock and signal distribution.

# **FUNCTIONAL BLOCK DIAGRAM**

# O1 O2 O3 O4 O6 O7 O7 O8 O9 O10

# **PIN CONFIGURATION**



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INDUSTRIAL TEMPERATURE RANGE

**MAY 2010** 

# ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	Terminal Voltage with Respect to GND	-0.5 to +5.5	V
VTERM <sup>(4)</sup>	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-60 to +60	mA

#### NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
  permanent damage to the device. This is a stress rating only and functional operation
  of the device at these or any other conditions above those indicated in the operational
  sections of this specification is not implied. Exposure to absolute maximum rating
  conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. Input terminals.
- 4. Outputs and I/O terminals.

# **CAPACITANCE** (TA = +25°C, f = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	3	4	pF
Соит	Output Capacitance	Vout = 0V	_	6	pF

## NOTE:

1. This parameter is measured at characterization but not tested.

# **PIN DESCRIPTION**

Pin Names	Description
IN	Clock Inputs
Ох	Clock Outputs

## **POWER SUPPLY CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Unit
ICCL	Quiescent Power Supply Current	Vcc = Max.		_	0.1	20	μΑ
Іссн	TTL Inputs HIGH	Vin = GND or Vcc					
∆lcc	Power Supply Current per	Vcc = Max.		_	45	300	μΑ
	Input HIGH	VIN = VCC -0.6V					
ICCD	Dynamic Power Supply Current	Vcc = 2.7V	150 MHz	_	40	_	μΑ
	per Output <sup>(3)</sup>	15 pF					/MHz
		Vcc = Max.	VIN = VCC	_	65	90	
Ic	Total Power Supply Current <sup>(4)</sup>	CL = 12pF	VIN = GND				mA
		All outputs toggling	VIN = VCC -0.6V	-	75	100	
		fi = 150MHz	VIN = GND				

#### NOTES:

- 1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 2.5V, +25°C ambient.
- 3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
- 4. IC = IQUIESCENT + INPUTS + IDYNAMIC

 $IC = ICC + \Delta ICC DHNT + ICCD (fi)$ 

Icc = Quiescent Current (Iccl, IccH and Iccz)

 $\Delta$ Icc = Power Supply Current for a TTL High Input (VIN = Vcc -0.6V)

DH = Duty Cycle for TTL Inputs High

NT = Number of TTL Inputs at DH

ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

fi = Input Frequency

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified Industrial: Ta = -40 $^{\circ}$ C to +85 $^{\circ}$ C, Vcc = 2.5V  $\pm$  0.2V

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Unit
VIH	Input HIGH Level			1.7	_	_	V
VIL	Input LOW Level			_	_	0.7	V
Iн	Input HIGH Current (Input pins)	Vcc = Max., VI = Vcc		_	_	±1	mA
lıL	Input LOW Current (Input pins)	Vcc = Max., Vi = GND		_	_	±1	mA
Vik	Clamp Diode Voltage	VCC = Min., IIN = -18mA		_	-0.7	-1	V
lodh	Output HIGH Current	$VCC = 2.5V$ , $VIN = VIH or VIL$ , $VO = 1.25V^{(3)}$		-25	-45	-100	mA
IODL	Output LOW Current	VCC = 2.5V, VIN = VIH or VIL	$VCC = 2.5V$ , $VIN = VIH or VIL$ , $VO = 1.25V^{(3)}$		55	120	mA
Vон	Output HIGH Voltage	Vcc = Min.	IOH = -1mA	Vcc-0.2	_	_	V
		VIN = VIH or VIL	IOH = -8mA	1.8 <sup>(5)</sup>	_	_	
Vol	Output LOW Voltage	Vcc = Min.	IoL = 1mA	_	_	0.4	V
		VIN = VIH or VIL	IoL = 8mA	_	_	0.6	
los	Short Circuit Current <sup>(4)</sup>	Vcc = Max., Vo = GND <sup>(3)</sup>		-25	-60	-135	mA

#### NOTES:

- 1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 2.5V, +25°C ambient.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. This parameter is guaranteed but not tested.
- 5. VoH = Vcc 0.6V at rated current.

# SWITCHING CHARACTERISTICS OVER OPERATING RANGE<sup>(1,2)</sup>

Following Conditions Apply Unless Otherwise Specified Industrial: Ta = -40 $^{\circ}$ C to +85 $^{\circ}$ C, Vcc = 2.5V  $\pm$  0.2V

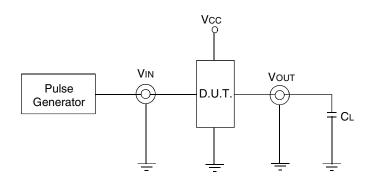
Symbol	Parameter	Conditions <sup>(3)</sup>	Min.	Тур.	Max.	Unit
tplh	Propagation Delay	CL = 22pF	_	3	3.5	ns
tphL		100 MHz				
tR	Output Rise Time		_	1	1.25	ns
tF	Output Fall Time		_	1	1.25	ns
tsk(o)	Same Device Output Pin-to-Pin Skew <sup>(4)</sup>		_	100	150	ps
tsk(p)	Pulse Skew <sup>(5)</sup>		_	250	300	ps
tsk(PP)	Part-to-Part Skew <sup>(6)</sup>		_	400	600	ps

Symbol	Parameter	Conditions <sup>(3,7)</sup>	Min.	Тур.	Max.	Unit
<b>t</b> PLH	Propagation Delay	CL = 12pF	_	2.4	2.7	ns
tphl.		150 MHz				
₽	Output Rise Time	1	_	1	1.2	ns
tF	Output Fall Time		_	1	1.2	ns
tsk(o)	Same Device Output Pin-to-Pin Skew <sup>(4)</sup>	1	_	100	150	ps
tsk(p)	Pulse Skew <sup>(5)</sup>		_	250	300	ps
tsk(PP)	Part-to-Part Skew <sup>(6)</sup>		_	400	600	ps

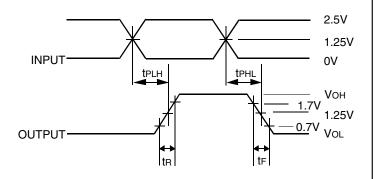
#### **NOTES**

- 1. tplh and tphl are production tested. All other parameters guaranteed but not production tested.
- 2. Propagation delay range indicated by Min. and Max. limit is due to Vcc, operating temperature and process parameters. These propagation delay limits do not imply skew.
- 3. See test circuits and waveforms.
- 4. Skew measured between all outputs under identical transitions and load conditions.
- 5. Skew measured is difference between propagation delay times tphl and tplh of same output under identical load conditions.
- 6. Part to part skew for all outputs given identical transitions and load conditions at identical Vcc levels and temperature.
- 7. Airflow of 1m/s is recommended for frequencies above 133MHz.

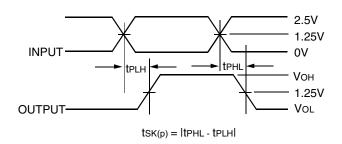
# **TEST CIRCUITS AND WAVEFORMS**



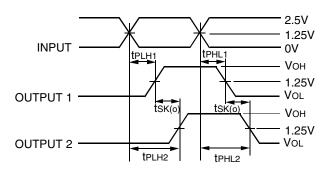
CL = Load Capacitance: Includes Jig and Probe Capacitance



Propagation Delay

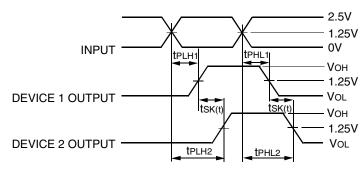


Pulse Skew - tsk(P)



tsk(o) = |tplh2 - tplh1| or |tphl2 - tphl1|

Output Skew - tsk(0)



tsk(t) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

Part-to-Part Skew - tSK(PP)

NOTE: Device 1 and device 2 are same package type and speed grade.

## **TEST CONDITIONS**

Symbol	Vcc = 2.5V ±0.2V	Unit
CL	22 <sup>(1)</sup>	pF
	12 <sup>(2)</sup>	
RT	Zout of pulse generator	Ω
tr/tr	1.25 <sup>(1)</sup>	ns
	1.2 <sup>(2)</sup>	

## **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

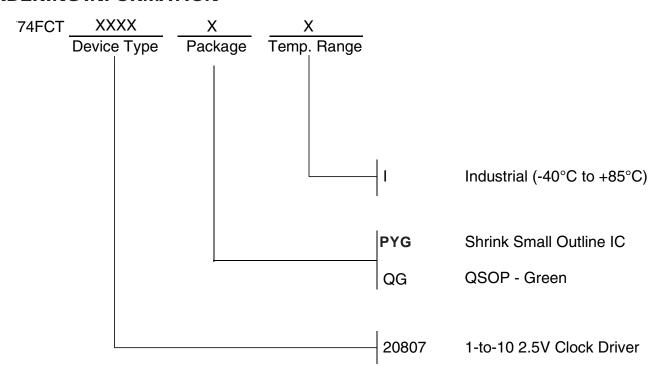
 $\mathsf{RT}$  = Termination resistance: should be equal to  $\mathsf{ZOUT}$  of the Pulse Generator.

tr / tr = Rise/Fall time of the input stimulus from the Pulse Generator.

## NOTES:

- 1. Test conditions at 100MHz.
- 2. Test conditions at 150MHz.

# **ORDERING INFORMATION**



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